

INTERNATIONAL STANDARD

NORME INTERNATIONALE



**Semiconductor devices – Semiconductor devices for energy harvesting and generation –
Part 7: Linear sliding mode triboelectric energy harvesting**

**Dispositifs à semiconducteurs – Dispositifs à semiconducteurs pour
récupération et génération d'énergie –
Partie 7: Récupération d'énergie triboélectrique en mode de coulissement
linéaire**



THIS PUBLICATION IS COPYRIGHT PROTECTED

Copyright © 2021 IEC, Geneva, Switzerland

All rights reserved. Unless otherwise specified, no part of this publication may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying and microfilm, without permission in writing from either IEC or IEC's member National Committee in the country of the requester. If you have any questions about IEC copyright or have an enquiry about obtaining additional rights to this publication, please contact the address below or your local IEC member National Committee for further information.

Droits de reproduction réservés. Sauf indication contraire, aucune partie de cette publication ne peut être reproduite ni utilisée sous quelque forme que ce soit et par aucun procédé, électronique ou mécanique, y compris la photocopie et les microfilms, sans l'accord écrit de l'IEC ou du Comité national de l'IEC du pays du demandeur. Si vous avez des questions sur le copyright de l'IEC ou si vous désirez obtenir des droits supplémentaires sur cette publication, utilisez les coordonnées ci-après ou contactez le Comité national de l'IEC de votre pays de résidence.

IEC Central Office
3, rue de Varembe
CH-1211 Geneva 20
Switzerland

Tel.: +41 22 919 02 11
info@iec.ch
www.iec.ch

About the IEC

The International Electrotechnical Commission (IEC) is the leading global organization that prepares and publishes International Standards for all electrical, electronic and related technologies.

About IEC publications

The technical content of IEC publications is kept under constant review by the IEC. Please make sure that you have the latest edition, a corrigendum or an amendment might have been published.

IEC publications search - webstore.iec.ch/advsearchform

The advanced search enables to find IEC publications by a variety of criteria (reference number, text, technical committee, ...). It also gives information on projects, replaced and withdrawn publications.

IEC online collection - oc.iec.ch

Discover our powerful search engine and read freely all the publications previews. With a subscription you will always have access to up to date content tailored to your needs.

IEC Just Published - webstore.iec.ch/justpublished

Stay up to date on all new IEC publications. Just Published details all new publications released. Available online and once a month by email.

Electropedia - www.electropedia.org

The world's leading online dictionary on electrotechnology, containing more than 22 000 terminological entries in English and French, with equivalent terms in 18 additional languages. Also known as the International Electrotechnical Vocabulary (IEV) online

IEC Customer Service Centre - webstore.iec.ch/csc

If you wish to give us your feedback on this publication or need further assistance, please contact the Customer Service Centre: sales@iec.ch.

A propos de l'IEC

La Commission Electrotechnique Internationale (IEC) est la première organisation mondiale qui élabore et publie des Normes internationales pour tout ce qui a trait à l'électricité, à l'électronique et aux technologies apparentées.

A propos des publications IEC

Le contenu technique des publications IEC est constamment revu. Veuillez vous assurer que vous possédez l'édition la plus récente, un corrigendum ou amendement peut avoir été publié.

Recherche de publications IEC -

webstore.iec.ch/advsearchform

La recherche avancée permet de trouver des publications IEC en utilisant différents critères (numéro de référence, texte, comité d'études, ...). Elle donne aussi des informations sur les projets et les publications remplacées ou retirées.

IEC online collection - oc.iec.ch

Découvrez notre puissant moteur de recherche et consultez gratuitement tous les aperçus des publications. Avec un abonnement, vous aurez toujours accès à un contenu à jour adapté à vos besoins.

IEC Just Published - webstore.iec.ch/justpublished

Restez informé sur les nouvelles publications IEC. Just Published détaille les nouvelles publications parues. Disponible en ligne et une fois par mois par email.

Electropedia - www.electropedia.org

Le premier dictionnaire d'électrotechnologie en ligne au monde, avec plus de 22 000 articles terminologiques en anglais et en français, ainsi que les termes équivalents dans 16 langues additionnelles. Egalement appelé Vocabulaire Electrotechnique International (IEV) en ligne.

Service Clients - webstore.iec.ch/csc

Si vous désirez nous donner des commentaires sur cette publication ou si vous avez des questions contactez-nous: sales@iec.ch.

INTERNATIONAL STANDARD

NORME INTERNATIONALE



**Semiconductor devices – Semiconductor devices for energy harvesting and generation –
Part 7: Linear sliding mode triboelectric energy harvesting**

**Dispositifs à semi-conducteurs – Dispositifs à semi-conducteurs pour
récupération et génération d'énergie –
Partie 7: Récupération d'énergie triboélectrique en mode de coulissement
linéaire**

INTERNATIONAL
ELECTROTECHNICAL
COMMISSION

COMMISSION
ELECTROTECHNIQUE
INTERNATIONALE

ICS 31.080.99

ISBN 978-2-8322-9469-7

**Warning! Make sure that you obtained this publication from an authorized distributor.
Attention! Veuillez vous assurer que vous avez obtenu cette publication via un distributeur agréé.**

CONTENTS

FOREWORD.....	4
1 Scope.....	6
2 Normative references	6
3 Terms and definitions	6
3.1 General terms.....	6
3.2 Triboelectric transducer	6
3.3 Characteristic parameters	7
4 Essential ratings and blank specification	10
4.1 Identification and type.....	10
4.2 Limiting values and operating conditions.....	10
4.3 Additional information	10
5 Test method	11
5.1 General.....	11
5.2 Electrical characteristics	12
5.2.1 Test procedure	12
5.2.2 Open-circuit voltage.....	13
5.2.3 Short-circuit current.....	14
5.2.4 Output voltage.....	14
5.2.5 Output current.....	14
5.2.6 Output power.....	15
5.2.7 Optimal load impedance	15
5.3 Mechanical characteristics	16
5.3.1 Test procedure.....	16
5.3.2 Contact area.....	17
5.3.3 Contact force.....	17
5.3.4 Displacement.....	18
5.3.5 Sliding speed.....	18
5.3.6 Relative humidity range	19
5.3.7 Temperature range	19
6 Test report.....	20
Annex A (informative) Linear sliding modes	22
A.1 Dielectric-to-dielectric sliding	22
A.2 Conductor-to-dielectric sliding.....	22
Annex B (informative) Example of experimental setup.....	23
Annex C (informative) Example of measurement for linear sliding mode triboelectric energy harvester.....	24
C.1 General.....	24
C.2 Linear sliding mode triboelectric energy harvester	24
C.2.1 Weight and dimension of tested sliding mode triboelectric energy harvesting device.....	24
C.2.2 Type, frequency, acceleration and displacement conditions of energy harvester	24
C.2.3 Measurement conditions and measurement results for open-circuit voltage	24
C.2.4 Measurement condition and measurement results for short-circuit current.....	25

C.2.5	Measurement conditions and measurement results for different acceleration.....	25
C.2.6	Measurement conditions and measurement results for different frequency	27
C.2.7	Measurement conditions and measurement results for different displacement	27
C.2.8	Measurement conditions and measurement results for output voltage and current at different loads	28
C.2.9	Measurement conditions and measurement results for output power.....	29
	Bibliography.....	30
	Figure 1 – Schematic of linear sliding mode triboelectric energy harvester.....	7
	Figure 2 – Equivalent circuit diagram of linear sliding mode triboelectric energy harvester	8
	Figure 3 – Measurement procedure for sliding mode triboelectric energy harvester.....	11
	Figure 4 – Test setup for the electrical characteristics of linear sliding mode triboelectric energy harvester.....	12
	Figure 5 – Instantaneous open-circuit output voltage characteristic.....	13
	Figure 6 – Instantaneous short-circuit output current characteristic.....	14
	Figure 7 – Output voltage and current at different loads	15
	Figure 8 – Output power characteristic at various external loads.....	15
	Figure 9 – Block diagram of a test setup for evaluating the reliability	16
	Figure 10 – Output voltage for different surface contact areas	17
	Figure 11 – Output voltage dependence on contact force.....	18
	Figure 12 – Output voltage for varying displacement between interfacing layers	18
	Figure 13 – Output voltage for different sliding speeds.....	19
	Figure 14 – Output voltage under different relative humidity.....	19
	Figure 15 – Output voltage at different temperature	20
	Figure A.1 – Operation modes of linear sliding mode triboelectric energy harvester	22
	Figure B.1 – Experimental setup for testing linear sliding mode triboelectric energy harvester	23
	Figure C.1 – Photographs of the triboelectric energy harvester	24
	Figure C.2 – Instantaneous open-circuit output voltage waveform.....	25
	Figure C.3 – Instantaneous short-circuit output current waveform	25
	Figure C.4 – Voltage waveform at 5 Hz frequency for different accelerations	26
	Figure C.5 – Output voltage characteristic at various accelerations.....	27
	Figure C.6 – Output voltage characteristic at different frequencies.....	27
	Figure C.7 – Output voltage for varying displacements between interfacing layers at 5 Hz frequency	28
	Figure C.8 – Output voltage and current at different loads	28
	Figure C.9 – Output power characteristic at various external loads	29
	Table 1 – Specification parameters for linear sliding mode triboelectric energy harvesters.....	10
	Table C.1 – Measurement conditions	24

INTERNATIONAL ELECTROTECHNICAL COMMISSION

**SEMICONDUCTOR DEVICES – SEMICONDUCTOR DEVICES
FOR ENERGY HARVESTING AND GENERATION –****Part 7: Linear sliding mode triboelectric energy harvesting**

FOREWORD

- 1) The International Electrotechnical Commission (IEC) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, IEC publishes International Standards, Technical Specifications, Technical Reports, Publicly Available Specifications (PAS) and Guides (hereafter referred to as "IEC Publication(s)"). Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- 2) The formal decisions or agreements of IEC on technical matters express, as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested IEC National Committees.
- 3) IEC Publications have the form of recommendations for international use and are accepted by IEC National Committees in that sense. While all reasonable efforts are made to ensure that the technical content of IEC Publications is accurate, IEC cannot be held responsible for the way in which they are used or for any misinterpretation by any end user.
- 4) In order to promote international uniformity, IEC National Committees undertake to apply IEC Publications transparently to the maximum extent possible in their national and regional publications. Any divergence between any IEC Publication and the corresponding national or regional publication shall be clearly indicated in the latter.
- 5) IEC itself does not provide any attestation of conformity. Independent certification bodies provide conformity assessment services and, in some areas, access to IEC marks of conformity. IEC is not responsible for any services carried out by independent certification bodies.
- 6) All users should ensure that they have the latest edition of this publication.
- 7) No liability shall attach to IEC or its directors, employees, servants or agents including individual experts and members of its technical committees and IEC National Committees for any personal injury, property damage or other damage of any nature whatsoever, whether direct or indirect, or for costs (including legal fees) and expenses arising out of the publication, use of, or reliance upon, this IEC Publication or any other IEC Publications.
- 8) Attention is drawn to the Normative references cited in this publication. Use of the referenced publications is indispensable for the correct application of this publication.
- 9) Attention is drawn to the possibility that some of the elements of this IEC Publication may be the subject of patent rights. IEC shall not be held responsible for identifying any or all such patent rights.

International Standard IEC 62830-7 has been prepared by IEC technical committee 47: Semiconductor devices.

The text of this International Standard is based on the following documents:

FDIS	Report on voting
47/2676/FDIS	47/2686/RVD

Full information on the voting for the approval of this International Standard can be found in the report on voting indicated in the above table.

This document has been drafted in accordance with the ISO/IEC Directives, Part 2.

A list of all parts in the IEC 62830 series, published under the general title *Semiconductor devices – Semiconductor devices for energy harvesting and generation*, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under "<http://webstore.iec.ch>" in the data related to the specific document. At this date, the document will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

IMPORTANT – The "colour inside" logo on the cover page of this document indicates that it contains colours which are considered to be useful for the correct understanding of its contents. Users should therefore print this document using a colour printer.

iTeh STANDARD PREVIEW (standards.iteh.ai)

[IEC 62830-7:2021](#)

<https://standards.iteh.ai/catalog/standards/sist/7dd3e871-305c-458b-a375-4ff21af24c89/iec-62830-7-2021>

SEMICONDUCTOR DEVICES – SEMICONDUCTOR DEVICES FOR ENERGY HARVESTING AND GENERATION –

Part 7: Linear sliding mode triboelectric energy harvesting

1 Scope

This part of IEC 62830 defines terms, definitions, symbols, configurations, and test methods that can be used to evaluate and determine the performance characteristics of linear sliding mode triboelectric energy harvesting devices for practical use. This document is applicable to energy harvesting devices for consumer, general industries, military and aerospace applications without any limitations on device technology and size.

2 Normative references

There are no normative references in this document.

3 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

ISO and IEC maintain terminological databases for use in standardization at the following addresses:

- IEC Electropedia: available at <http://www.electropedia.org/>
- ISO Online browsing platform: available at <http://www.iso.org/obp>

3.1 General terms

3.1.1

linear sliding

physical sliding of one material on another material in horizontal direction

3.1.2

sliding-based energy harvester

energy transducer that transforms physical sliding energy into electrical energy

Note 1 to entry: A linear sliding mode triboelectric energy harvester to convert linear sliding to electricity comprises dielectric materials, a surface electrode, an external load, and a relative displacement between dielectric materials as shown in Figure 1. The sliding makes the two dielectric material surfaces come into physical touch, and relative displacement makes the gap between those two materials. The top and bottom electrodes on the two dielectric materials harvest charges generated from the coupling of triboelectrification and electrostatic induction. The triboelectric charges are generated by the charge transfer between two thin organic/inorganic films that exhibit distinct surface electron affinity, and the potential difference results from the separation of the triboelectric charges; under short-circuit conditions, electrons are driven to flow between two electrodes attached on the back side of the films through the load in order to balance the potential difference resulting from mechanical action.

3.2 Triboelectric transducer

3.2.1

triboelectric effect

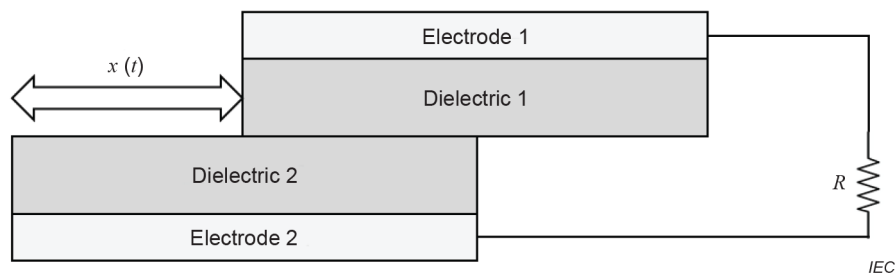
type of contact electrification in which certain materials become electrically charged after they come into frictional contact with a different material

3.2.2 triboelectric series

list that ranks various materials according to their tendency to gain or lose electrons

3.2.3 triboelectric transducer

energy converter to generate electricity from mechanical energy by means of the triboelectric effect



Key

Configuration of energy harvester

$x(t)$ displacement

R external load

Figure 1 – Schematic of linear sliding mode triboelectric energy harvester

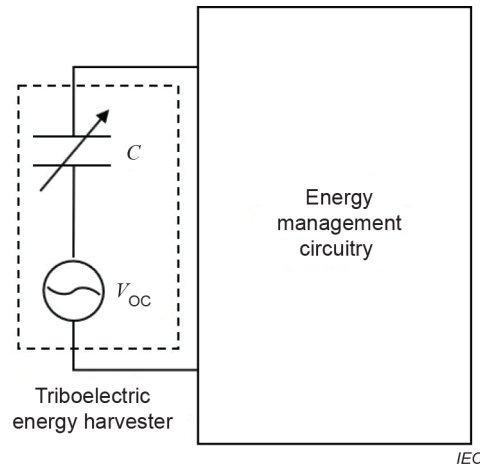
Note 1 to entry: A linear sliding mode triboelectric energy harvester can be divided into parts as shown in Figure 1. The equivalent circuit consists of capacitance C which stores charge as $+Q$ and $-Q$, open-circuit voltage source V_{oc} and external load R . Considering the materials to be used as the pair of the triboelectric layers, the sliding mode triboelectric nanogenerator (TENG) has two types: dielectric-to-dielectric and conductor-to-dielectric. The fundamentals of these two types are reported under Annex A.

3.3 Characteristic parameters

3.3.1 equivalent circuit

electrical circuit block diagram that has the same output voltage from relative displacement-based linear sliding mode triboelectric energy harvester in the immediate neighborhood of the acting force

Note 1 to entry: An equivalent circuit diagram of linear sliding mode triboelectric energy harvester is shown in Figure 2.



Key parameters

- C capacitance
- V_{oc} open-circuit voltage

Figure 2 – Equivalent circuit diagram of linear sliding mode triboelectric energy harvester

3.3.2

V - Q - x relationship

relationship between the triboelectric output voltage, the amount of charge transferred between electrodes and the separation distance between tribological material surfaces

Note 1 to entry: Owing to the electrical potential superposition principle, the total voltage difference between the two electrodes can be given by Formula (1): [IEC 62830-7:2021](https://standards.iteh.ai/catalog/standards/sist/7dd3e871-305c-458b-a375-4ff21af24c89/iec-62830-7-2021)

<https://standards.iteh.ai/catalog/standards/sist/7dd3e871-305c-458b-a375-4ff21af24c89/iec-62830-7-2021>

$$V = -\frac{l}{C}Q + V_{oc} = -\frac{d_0}{w\epsilon_0(l-x)}Q + \frac{\sigma d_0 x}{\epsilon_0(l-x)} \quad (1)$$

where, d_0 is effective dielectric thickness, w is dielectric width, ϵ_0 is the permittivity of the medium, σ is the surface charge density, l is the length of the dielectric material, x is the lateral separation distance, and other parameters are as defined before.

3.3.3

open-circuit voltage

V_{oc}

electrical potential difference relative to a reference node of an energy harvester when there is no external load connected to the terminal of the energy harvester

Note 1 to entry: The theoretical V_{oc} expression for the linear sliding mode triboelectric energy harvester is given by Formula (2):

$$V_{oc} = \frac{\sigma x}{\epsilon_0(l-x)} \left(\frac{d_1}{\epsilon_{r1}} + \frac{d_2}{\epsilon_{r2}} \right) \quad (2)$$

where, d_1 and d_2 are the dielectric thickness, ϵ_{r1} and ϵ_{r2} are the permittivity of dielectric material 1 and 2, respectively, and the other parameters are as defined before.

3.3.4

short-circuit current

I_{sc}

current measured through the terminals of the energy harvester from induced excitation without external load

Note 1 to entry: The theoretical I_{sc} expression for linear sliding mode TENG is given by Formula (3)**Error! Bookmark not defined.**

$$I_{sc} = \sigma w \frac{dx}{dt} = \sigma w v(t) \quad (3)$$

where w is the thickness of the dielectric material, $v(t)$ is the sliding speed of the triboelectric layer, and the other parameters are as defined before.

3.3.5 output voltage

V

electrical potential difference relative to a reference node of an energy harvester when an external load is connected to the terminal of the energy harvester

3.3.6 output current

I

<energy harvester device> current through the external load connected to the terminal of an energy harvester

3.3.7 output power

P

electrical power transferred to the external load connected to the terminal of an energy harvester

Note 1 to entry: The theoretical expression for the output power of linear sliding mode TENG is given by Formula (4):

<https://standards.iteh.ai/catalog/standards/sist/7dd3e871-305c-458b-a375-4ff21af24c89/iec-62830-7-2021>

$$P = VI \quad (4)$$

3.3.8 optimal load impedance

R_{opt}

specified value of the external load for transferring the largest electrical energy from the energy harvester

3.3.9 contact area

area of physical contact of one object with the other object

Note 1 to entry: When two objects touch, a certain portion of their surface areas will be in contact with each other. The contact area is the fraction of this area that consists of the atoms of one object in contact with the atoms of the other object. Because objects are never perfectly flat because of asperities, the actual contact area (on a microscopic scale) is usually much less than the contact area apparent on a macroscopic scale. The contact area may depend on the normal force between the two objects because of deformation.

3.3.10 contact force

applied force in the normal direction to the surface owing to friction at the interface of two triboelectric material surfaces

3.3.11 displacement

x

moving distance of one material from its original position

**3.3.12
sliding speed**

v

displacement per unit time of one material over another material surface while maintaining continuous contact

**3.3.13
relative humidity range**

range of humidity as measured on the enclosure over which the energy harvester will not sustain permanent damage though not necessarily functioning within certain tolerances

**3.3.14
temperature range**

range of temperatures as measured on the enclosure over which the energy harvester will not sustain permanent damage though not necessarily functioning within the specified tolerances

4 Essential ratings and blank specification

4.1 Identification and type

The linear sliding mode triboelectric energy harvester shall be clearly and durably marked with the following information, in the order given below:

- a) year and week (or month) of manufacture;
- b) manufacturer's name or trademark;
- c) terminal identification (optional);
- d) serial number;
- e) factory identification code (optional).

4.2 Limiting values and operating conditions

Characteristic parameters should be listed in as shown in Table 1. The manufacturer shall clearly announce the operating conditions and their limitation for energy harvesting. The limiting value is the maximum operating cycle to ensure the operation of the linear sliding mode energy harvester for power generation without any damage.

Table 1 – Specification parameters for linear sliding mode triboelectric energy harvesters

Parameter	Symbol	Min.	Max.	Unit	Measuring conditions
<i>Insert name of characteristic parameters</i>					

4.3 Additional information

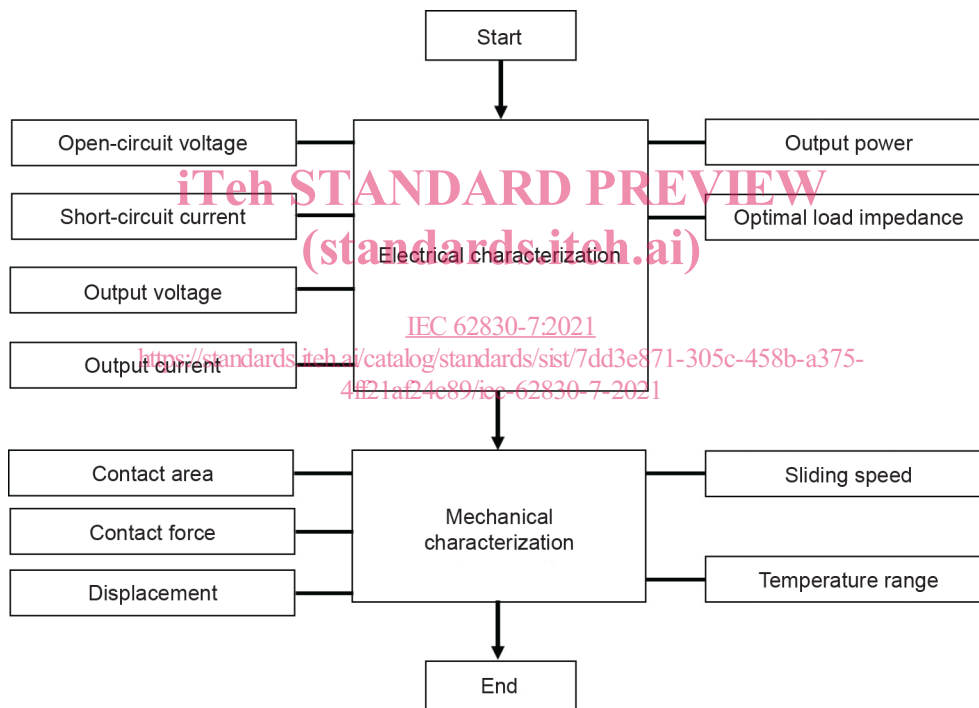
Some additional information should be given, such as equivalent circuits (relative displacement, internal impedance, output voltage, current, and power, etc.), handling precautions, physical information (outline dimensions, terminals, etc.), accessories, installation guide, package information, PCB interface and mounting information.

5 Test method

5.1 General

Basically, general test procedures for a linear sliding-based energy harvester are performed as shown in Figure 3. After the linear sliding mode triboelectric energy harvester has been mounted on a test fixture, it is measured by using an oscilloscope/electrometer and a linear variable differential transformer (LVDT). For measuring and characterizing these devices accurately, ultra-high-impedance meters should be used. Before connecting the triboelectric energy harvester to the test fixture, measuring meters shall be calibrated. After calibration, connect a test cable to the energy harvester test fixture mounted on an actuator or a force gauge. The output voltage or current reading on the display of the meters is carefully taken, together with induced linear displacement, which is measured by the LVDT.

After mounting the energy harvester on an actuator, the electrical characteristics are measured by using a meter or equivalent equipment. If the electrical characteristic measurements are satisfactory, the reliability test is performed under the relative humidity range with thermal cycling and various excitations.



IEC

Key			
Procedure	Reference subclause	Procedure	Reference subclause
Start			
Electrical characterization		Mechanical characterization	
Open-circuit voltage	3.3.3 and 5.2.2	Contact area	3.3.9 and 5.3.2
Short-circuit current	3.3.4 and 5.2.3	Contact force	3.3.10 and 5.3.3
Output voltage	3.3.5 and 5.2.4	Displacement	3.3.11 and 5.3.4
Output current	3.3.6 and 5.2.5	Sliding speed	3.3.12 and 5.3.5
Output power	3.3.7 and 5.2.6	Relative humidity range	3.3.13 and 5.3.6
Optimal load impedance	3.3.8 and 5.2.7	Temperature range	3.3.14 and 5.3.7

Figure 3 – Measurement procedure for sliding mode triboelectric energy harvester

5.2 Electrical characteristics

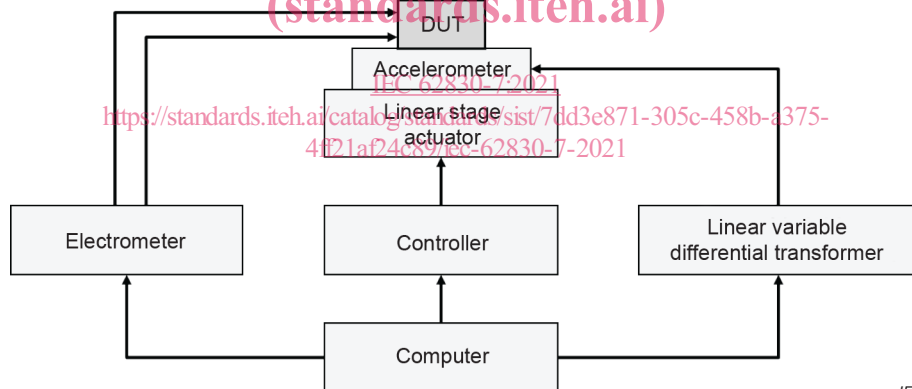
5.2.1 Test procedure

Figure 4 shows a test setup for measuring the electrical characteristics of a linear sliding mode triboelectric energy harvester. To measure the electrical characteristics of the energy harvester, the device shall be mounted on a linear stage actuator as shown in Figure 4. When a linear displacement is applied to the device, an output voltage or current across an external load is measured. The peak-to-peak value, RMS value, and frequency information for the instantaneous output waveform of the harvester can be obtained from the measuring equipment.

A description of two different linear sliding modes is given in Annex A. An example of experimental setup is described in Annex B. An example of measurement for a linear sliding mode triboelectric energy harvester is described in Annex C.

The following test procedure is performed:

- 1) A specified relative sliding is induced to the energy harvester.
- 2) The voltage or current across the external load, which is connected to the terminals of the energy harvester, is measured using a voltage or current meter.
- 3) The voltage and current are measured with various excitation by adjusting the parameters via a computer.
- 4) The maximum voltage and current are derived from various external loads to find the optimal load.



IEC

Key

Input exciter and meters to monitor

DUT: device under test	energy harvester
Electrometer	to detect voltage, current, amount of charge transfer and resistance
Computer	to select input excitation and to get data points
Accelerometer	to measure the input excitation
Linear stage actuator	to apply linear motion as input in energy harvester
Controller	to control linear stage actuator
Linear variable differential transformer	to measure displacement between layers of energy harvesting device

Figure 4 – Test setup for the electrical characteristics of linear sliding mode triboelectric energy harvester

5.2.2 Open-circuit voltage

The objective of this test is to evaluate the instantaneous output voltage across the terminals of the energy harvester without external load. The input frequency, contact force, sliding speed, displacement, contact area, and input waveform for this measurement are 1,6 Hz, 20 N, 60 mm/s, 4 cm, 4 mm², and sinusoidal wave, respectively. When measuring open-circuit voltage, the input impedance of the voltage meter shall be recorded. Figure 5 shows the measured instantaneous peak-peak open-circuit output voltage profiles as a function of time. When measuring voltage, the input impedance of the meter shall be many decades higher than the impedance of the voltage source. For example, if the meter's input impedance is only 1 G Ω (typical of DMMs), and the source of voltage has 10 M Ω of impedance, then the meter will introduce a 1 % error owing to its relatively low input impedance. In contrast, an electrometer with 10¹⁴ Ω input impedance will cause only a 0,000 01 % error. Therefore, an input impedance of 10¹⁴ Ω is recommended for electrical measurements. Furthermore, parasitic capacitances in the system easily cause a long charging-discharging time constant. For example, if the capacitance is only 10 pF, a test resistance of 1 T Ω will result in a time constant of 10 s. Thus, a settling time of 50 s would be required for the reading to settle to within 1 % of final value. In order to minimize settling times when measuring high resistance values, shunt capacitance in the system shall be kept to an absolute minimum by keeping connecting cables as short as possible. The effect of voltage leakage and parasitic capacitance can be diminished further by shielding the cables and guarding the measurement device. Therefore, a shielded, low noise, triax cable (model 237-ALG-2 ¹) with guard mode ON on the Electrometer 6514² is recommended to be used for electrical measurements.

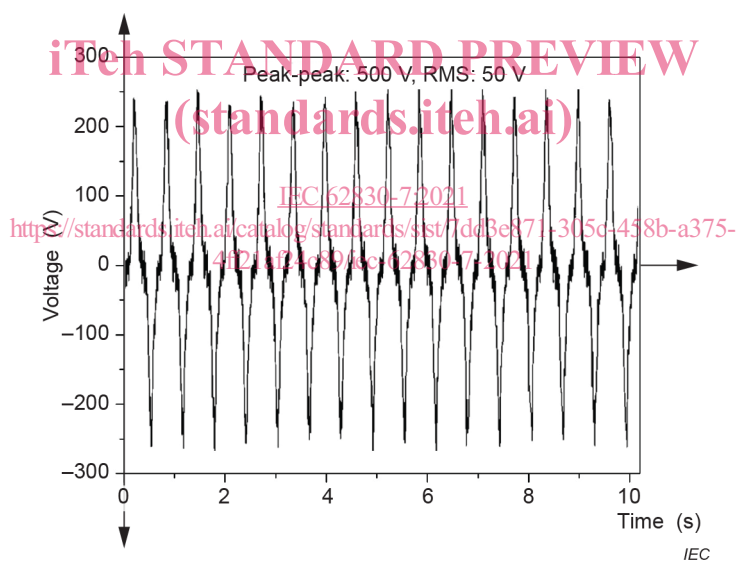


Figure 5 – Instantaneous open-circuit output voltage characteristic

- ¹ 237-ALG-2 is the trademark of a product supplied by Keithley Instruments Inc. This information is given for the convenience of users of this document and does not constitute an endorsement by IEC of the product named. Equivalent products may be used if they can be shown to lead to the same results.
- ² Electrometer 6514 is the trademark of a product supplied by Keithley Instruments Inc. This information is given for the convenience of users of this document and does not constitute an endorsement by IEC of the product named. Equivalent products may be used if they can be shown to lead to the same results.